



ITZ
Docket: MXIC-P910270

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application:

Chen et al.

U.S. Serial No: 10/661,089

Filed: September 10, 2003

For: METHOD FOR MITIGATING CHEMICAL
VAPOR DEPOSITION PHOSPHORUS
DOPING OXIDE SURFACE INDUCED
DEFECTS

/

Examiner: Hoang, Quoc Dinh

Group Art Unit: 2818

TRANSMITTAL

Sir:

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first class mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, or facsimile transmitted to: Commissioner for Patents at fax number (571) 273-8300 on December 23, 2005.

Submitted herewith are:

1. Return Receipt postcard;
2. Check No. 21626 in the amount of \$1020.00;
3. Amendment (9 pages);
4. Deposit Account Authorization: The Commissioner is hereby authorized to charge any needed fees to deposit account 50-1600.

Each of the 4 above-identified documents are enclosed herewith.

Respectfully submitted,

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Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Dear Sir:

In response to the Office Action mailed June 28, 2005, Applicants respectfully request that the following amendments be entered in the above-identified patent application:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.